

## ECEn 452. Experiments in Integrated Circuit Development

<b>Catalog Description:</b>	<b>ECEn 452. Experiments in Integrated Circuit Development. (1:0:3) W</b> Measurements of key silicon properties and fabrication of integrated circuits.	
<b>Course Type:</b>	Engineering Topics	
<b>Prerequisites:</b>	ECEn 450 or concurrent enrollment.	
<b>Textbooks and/or other required materials</b>	S.M. Sze, <i>Semiconductor Devices, Physics and Technology - 2nd Edition</i> , John Wiley & Sons, 2002, ISBN 0-471-33372-7.	
<b>Topics Covered:</b>	Basic Semiconductor fabrication principles including lithography, wet and dry etching, thin film deposition, oxide growth, and dopant diffusion. Hands-on activities include fabricating and measuring MOSFETs	
<b>Course Competencies:</b>	Ability to analyze and interpret data measured from fabricated devices	Outcome 2
	Ability to design processes for fabrication of MOSFET devices.	Outcome 3
	Ability to use modern microelectronics fabrication equipment.	Outcome 11
<b>Schedule:</b>	Lectures: (None) Laboratory: 3 hours per week TA Recitations: (None)	
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<b>Date:</b>	June 24, 2008	